NSN 5962-01-064-5759

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View Online at https://aerobasegroup.com/nsn/5962-01-064-5759 **Body Length:** Between 0.755 inches and 0.790 inches **Body Width:** Between 0.265 inches and 0.300 inches **Body Height:** Between 0.155 inches and 0.175 inches **Maximum Power Dissipation Rating:** 650.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Strategic weapon systems (poseidon and trident). **Features Provided:** Hermetically sealed and monolithic and positive outputs and 3-state output and w/enable and w/storage and programmable and programmed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Criticality Code Justification:** Feat **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:**

Unknown

Special Features:

Weapon system essential

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

Fiig:

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